

WHAT IS CLAIMED IS:

1. An optical gain correction filter comprising:  
a multilayer film structure formed by stacking a  
plurality of thin films with different diffractive  
indexes on a light transmitting board, wherein

5 when the light with the wavelength  $\lambda$  enters at  
the incident angle  $\theta$ , the transmissivity is assumed to  
be  $T_1(\lambda, \theta)$  ( $0 \leq T_1(\lambda, \theta) \leq 1$ ), and the thickness  
of each thin film is set to increase the transmissivity  
10  $T_1(\lambda_0, \theta)$  when the incident angle  $\theta$  increases close  
to the predetermined maximum incident angle  $\theta_{\max}$  with  
respect to the incident light with the wavelength  $\lambda_0$   
entering the multilayer structure.

2. The optical gain correction filter according  
15 to claim 1, wherein the thin films which construct the  
multilayer film structure are formed by alternately  
stacking  $\text{SiO}_2$  with the refractive index of 1.46 and  
 $\text{TiO}_2$  with the refractive index of 2.3.

3. The optical gain correction filter according  
20 to claim 2, having the transmissivity of 70% or lower  
so that the wavelength  $\lambda_0$  of the incident light  
coincides with the position of a ripple of a band pass  
filter.

4. The optical gain correction filter according  
25 to claim 1, wherein the thin films which construct the  
multilayer film structure are formed by alternately  
combining one of  $\text{SiO}_2$ ,  $\text{MgF}_2$ ,  $\text{Al}_2\text{O}_3$  or  $\text{SiO}$  and one of

TiO<sub>2</sub>, CeO<sub>2</sub>, ZrO<sub>2</sub>, Ta<sub>2</sub>O<sub>5</sub> or ZnS.

5. An optical gain correction filter comprising:  
a multilayer film structure formed by stacking a  
plurality of thin films with different diffractive  
indexes on a light transmitting board, wherein

when the light with the wavelength  $\lambda$  enters at  
the incident angle  $\theta$ , the transmissivity is assumed to  
be  $T_1(\lambda, \theta)$  ( $0 \leq T_1(\lambda, \theta) \leq 1$ ), and the thickness  
of each thin film is set to increase the transmissivity  
10  $T_1(\lambda, \theta_0)$  when the wavelength  $\lambda$  increases close to  
the predetermined maximum wavelength  $\lambda_{\max}$  with respect  
to the incident light entering the multilayer structure  
at the incident angle of  $\theta_0$ .

6. The optical gain correction filter according  
15 to claim 5, wherein the thin films which construct the  
multilayer film structure are formed by alternately  
stacking SiO<sub>2</sub> with the refractive index of 1.46 and  
TiO<sub>2</sub> with the refractive index of 2.3.

7. The optical gain correction filter according  
20 to claim 6, having the transmissivity of 70% or lower  
so that the wavelength  $\lambda_0$  of the incident light  
coincides with the position of the ripple of a band  
pass filter.

8. The optical gain correction filter according  
25 to claim 5, wherein the thin films which construct the  
multilayer film structure are formed by alternately  
combining one of SiO<sub>2</sub>, MgF<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub> or SiO and one of

TiO<sub>2</sub>, CeO<sub>2</sub>, ZrO<sub>2</sub>, Ta<sub>2</sub>O<sub>5</sub> or ZnS.

9. An optical gain correction filter comprising:  
a multilayer film structure formed by stacking a  
plurality of thin films with different diffractive  
indexes on a light transmitting board, wherein

5 when the light with the wavelength  $\lambda$  enters at  
the incident angle  $\theta$ , the reflectivity is assumed to  
be  $R_1(\lambda, \theta)$  ( $0 \leq R_1(\lambda, \theta) \leq 1$ ), and the thickness  
of each thin film is set to increase the reflectivity  
10  $R_1(\lambda_0, \theta)$  when the incident angle  $\theta$  increases close  
to the predetermined maximum incident angle  $\theta_{\max}$  with  
respect to the incident light with the wavelength  $\lambda_0$   
entering the multilayer structure.

10. The optical gain correction filter according  
15 to claim 9, wherein the thin films which construct the  
multilayer film structure are formed by alternately  
stacking SiO<sub>2</sub> with the refractive index of 1.46 and  
TiO<sub>2</sub> with the refractive index of 2.3.

11. The optical gain correction filter according  
20 to claim 10, having the transmissivity of 70% or lower  
so that the wavelength  $\lambda_0$  of the incident light  
coincides with the position of the ripple of a band  
pass filter.

12. The optical gain correction filter according  
25 to claim 9, wherein the thin films which construct the  
multilayer film structure are formed by alternately  
combining one of SiO<sub>2</sub>, MgF<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub> or SiO and one of

TiO<sub>2</sub>, CeO<sub>2</sub>, ZrO<sub>2</sub>, Ta<sub>2</sub>O<sub>5</sub> or ZnS.

13. An optical gain correction filter comprising:  
a multilayer film structure formed by stacking a  
plurality of thin films with different diffractive  
indexes on a light transmitting board, wherein

5 when the light with the wavelength  $\lambda$  enters at  
the incident angle  $\theta$ , the reflectivity is assumed to  
be  $R_1(\lambda, \theta)$  ( $0 \leq R_1(\lambda, \theta) \leq 1$ ), and the thickness  
of each thin film is set to increase the reflectivity  
10  $R_1(\lambda, \theta_0)$  when the wavelength  $\lambda$  increases close to  
the predetermined maximum wavelength  $\lambda_{\max}$  with respect  
to the incident light entering the multilayer structure  
at the incident angle of  $\theta_0$ .

14. The optical gain correction filter according  
15 to claim 13, wherein the thin films which construct the  
multilayer film structure are formed by alternately  
stacking SiO<sub>2</sub> with the refractive index of 1.46 and  
TiO<sub>2</sub> with the refractive index of 2.3.

15. The optical gain correction filter according  
20 to claim 14, having the transmissivity of 70% or lower  
so that the wavelength  $\lambda_0$  of the incident light  
coincides with the position of the ripple of a band  
pass filter.

16. The optical gain correction filter according  
25 to claim 14, wherein the thin films which construct the  
multilayer film structure are formed by alternately  
combining one of SiO<sub>2</sub>, MgF<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub> or SiO and one of

TiO<sub>2</sub>, CeO<sub>2</sub>, ZrO<sub>2</sub>, Ta<sub>2</sub>O<sub>5</sub> or ZnS.

17. An optical apparatus comprising,  
a semiconductor laser light source with the  
wavelength of  $\lambda_0$ ;

5 a scanning section for scanning a laser beam  
radiated from the semiconductor laser light source;

a photodetector for receiving scattered light from  
the scanned laser beam; and

an optical gain correction filter, which is  
10 arranged on an optical path from the semiconductor  
laser light source to the photodetector, and has a  
multilayer film structure formed by stacking  
a plurality of thin films with different diffractive  
indexes on a light transmitting board, in which when  
15 light with the wavelength  $\lambda$  enters at the incident  
angle  $\theta$ , the transmissivity is assumed to be  $T_1(\lambda, \theta)$   
( $0 \leq T_1(\lambda, \theta) \leq 1$ ), and the thickness of said  
each thin film is set to increase the transmissivity  $T_1$   
( $\lambda_0, \theta$ ) when the incident angle  $\theta$  increases close to  
20 the predetermined maximum incident angle  $\theta_{\max}$  with  
respect to the incident light with the wavelength  $\lambda_0$   
entering the multilayer structure; wherein

the optical gain correction filter is arranged in  
the direction to increase the transmissivity  $T_1(\lambda, \theta)$   
25 as the incident angle of the scattered light increases.

18. The optical apparatus according to claim 17,  
wherein the optical gain correction filter is provided

on the optical path, and on the reflection surface of the scanning section or in front of the photodetector.

19. An optical apparatus comprising,

5 a semiconductor laser light source with the wavelength of  $\lambda_0$ ;

a scanning section for scanning a laser beam radiated from the semiconductor laser light source;

a photodetector for receiving scattered light from the scanned laser beam; and

10 an optical gain correction filter, which is arranged on an optical path from the semiconductor laser light source to the photodetector, and has a multilayer film structure formed by stacking a plurality of thin films with different diffractive indexes on a light emitting board, in which when light with the wavelength  $\lambda$  enters at the incident angle  $\theta$ , the transmissivity is assumed to be  $T_1(\lambda, \theta)$  ( $0 \leq T_1(\lambda, \theta) \leq 1$ ), and the thickness of said each thin film is set to increase the transmissivity  $T_1(\lambda, \theta_0)$  when  
15 the wavelength  $\lambda$  increases close to the predetermined maximum wavelength  $\lambda_{\max}$  with respect to the incident light entering the multilayer structure at the incident angle of  $\theta_0$ ; wherein

20 the optical gain correction filter is arranged in the direction to increase the transmissivity  $T_1(\lambda, \theta)$  as the incident angle of the scattered light increases.

20. The optical apparatus according to claim 19,

wherein the optical gain correction filter is provided on the optical path, and on the reflection surface of the scanning section or in front of the photodetector.

21. An optical apparatus comprising,

5           a semiconductor laser light source with the wavelength of  $\lambda_0$ ;

          a scanning section for scanning a laser beam radiated from the semiconductor laser light source;

          a photodetector for receiving a scattered light  
10       from the scanned laser beam; and

          an optical gain correction filter, which is arranged on an optical path from the semiconductor laser light source to the photodetector, and has a multilayer film structure formed by stacking a  
15       plurality of thin films with different diffractive indexes on a board to transmit a light, in which when a light with the wavelength  $\lambda$  enters at the incident angle  $\theta$ , the reflectivity is assumed to be  $R_1(\lambda, \theta)$  ( $0 \leq R_1(\lambda, \theta) \leq 1$ ), and the thickness of said each  
20       thin film is set to increase the reflectivity  $R_1(\lambda_0, \theta)$  when the incident angle  $\theta$  increases close to the predetermined maximum incident angle  $\theta_{\max}$  with respect to the incident light with the wavelength  $\lambda_0$  entering the multilayer structure; wherein

25           the optical gain correction filter is arranged in the direction to increase the reflectivity  $R_1(\lambda, \theta)$  as the incident angle of the scattered light increases.

22. The optical apparatus according to claim 21, wherein the optical gain correction filter is provided on the optical path, and on the reflection surface of the scanning section or in front of the photodetector.

5        23. An optical apparatus comprising,

        a semiconductor laser light source with the wavelength of  $\lambda_0$ ;

        a scanning section for scanning a laser beam radiated from the semiconductor laser light source;

10        a photodetector for receiving scattered light from the scanned laser beam; and

        an optical gain correction filter, which is arranged on an optical path from the semiconductor laser light source to the photodetector, and has a  
15        multilayer film structure formed by stacking a plurality of thin films with different diffractive indexes on a light transmitting board, in which when light with the wavelength  $\lambda$  enters at the incident angle  $\theta$ , the reflectivity is assumed to be  $R_1(\lambda, \theta)$   
20        ( $0 \leq R_1(\lambda, \theta) \leq 1$ ), and the thickness of said each thin film is set to increase the reflectivity  $R_1(\lambda, \theta_0)$  when the wavelength  $\lambda$  increases close to the predetermined maximum wavelength  $\lambda_{\max}$  with respect to the incident light entering the multilayer structure at  
25        the incident angle of  $\theta_0$ ; wherein

        the optical gain correction filter is arranged in the direction to increase the reflectivity  $R_1(\lambda, \theta)$



as the incident angle of the scattered light increases.

24. The optical apparatus according to claim 23,  
wherein the optical gain correction filter is provided  
on the optical path, and on the reflection surface of  
5 the scanning section or in front of the photodetector.